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1 Hyperspectral infrared imaging of surface phonon-

² polaritons in SrTiO₃

3 D. J. Lahneman and M. M. Qazilbash*

4 Department of Physics, College of William & Mary, Williamsburg, Virginia 23187-8795, USA

5 * mmqazilbash@wm.edu

6 Abstract:

7 Polaritons have a demonstrated impact to nanophotonic applications in the mid-infrared through 8 visible spectral range. Surface phonon polaritons (SPhPs) offer a way to bring the potential of 9 polaritons to the longer infrared wavelengths. Strontium titanate (STO) is a perovskite polar 10 dielectric with diverse technologically advantageous properties and it can support SPhPs in a 11 uniquely broad spectral range of the far-infrared. Despite these advantages, STO has mostly been 12 overlooked as a nanophotonic material. In this work we investigate SPhP propagation in STO in 13 the far-infrared through mid-infrared spectral range using broadband, near-field nano-14 spectroscopy (nano-FTIR). We developed a tabletop, laser sustained plasma light source that 15 enabled us to obtain amplitude and phase resolved hyperspectral line scan maps of SPhPs across 16 the surface of the STO sample. Analytical modeling of experimental data reveals the dispersion 17 characteristics of SPhPs in STO. This work establishes STO as a platform for perovskite-based 18 broadband far-infrared and terahertz nanophotonics.

I. INTRODUCTION

20 Polaritons are quasiparticles formed from the strong coupling of photons with charge excitations in materials such as plasmons, phonons, and excitons.¹⁻⁴ Polaritons have already 21 22 made significant impact in many areas of research including efforts towards room temperature Bose-Einstein condensation.^{4,5} superfluidity and quantized vortices.^{6,7} room temperature 23 polariton lasers,^{8,9} all optical transistors,¹⁰ and efficient energy conversion.¹¹ Plasmon and 24 25 exciton polaritons have demonstrated utility from the mid-infrared through visible. However, as 26 the wavelengths get further into the less explored far-infrared and terahertz spectral range, 27 limitations occur due to lack of available sources and detectors. It is in this spectral range that 28 surface phonon polaritons (SPhPs) show great potential to carry over the technological 29 advantages of polaritons. SPhPs are surface electromagnetic waves that result from the coupling 30 of photons with optical phonons in dielectrics. In contrast, surface plasmon polaritons (SPPs) are 31 surface electromagnetic waves that arise from the coupling of photons to free electrons in metals. 32 SPhPs arise in a range of frequencies dictated by the optical phonons of the dielectric, which 33 often occur below 1000 cm⁻¹ frequency. SPhPs already have proven applications such as coherent thermal emission,¹² enhanced light-matter interactions,¹³ high-density infrared data 34 storage,¹⁴ metamaterials,¹⁵⁻¹⁷ terahertz wave generation,¹⁸ and electrically pumped SPhP based 35 lasers.¹⁹ 36

The far-infrared SPhP spectrum has recently been experimentally resolved in strontium titanate (STO).²⁰⁻²³ STO is a highly stable material. It is a polar dielectric that exhibits a diverse range of electronic and optical properties that make it an exciting technological material. STO is transparent to visible light with a band gap of ~3.2 eV while having excellent paraelectric, dielectric, and optoelectronic properties.²⁴⁻²⁶ Upon doping with electrons, either through niobium

or iron doping or via oxygen vacancies, STO can transition to a very stable metallic state.²⁷⁻³⁴ 42 43 Furthermore, STO can support exotic states such as superconductivity and a two-dimensional electron gas.³⁵⁻³⁸ As a cubic perovskite, STO is a common substrate for lattice matching or to 44 provide strain to a number of functional oxide films.³⁹ Many advancements have been made in 45 46 obtaining low impurity and high crystalline quality bulk samples of STO as well as treatments to 47 produce high quality surfaces. However, very little work has been done towards realizing the 48 potential of STO as an infrared nanophotonic platform. Only recently has STO been put in 49 perspective as a unique polar dielectric in the infrared due to its ability to support both a midinfrared SPhP and a far-infrared SPhP.^{21,40} Most work discussing STO has been constrained to 50 51 the mid-infrared, only covering the higher frequency SPhP without probing wavelengths longer than a free space wavelength of $\sim 20 \text{ }\mu\text{m}.^{22,23,41}$ 52

53 For both SPPs and SPhPs, the conditions for a propagating surface wave are that the real part (ε_1) of the dielectric function is negative while the imaginary part (ε_2) is small. For SPhPs in 54 55 polar dielectrics, these conditions are met between the transverse optical (TO) and longitudinal optical (LO) phonons, called the Reststrahlen band.⁴² Figure 1(a) displays the reflectance of STO 56 57 showing two Reststrahlen bands. The mid-infrared (mid-IR) band manifests between the TO and 58 LO phonon modes primarily related to motion of the lighter oxygen atoms while the far-infrared 59 (far-IR) band results from a combined contribution of the TO and LO phonon modes primarily related to motion of the heavier strontium and titanium atoms.⁴³ Figure 1(b) shows the real and 60 61 imaginary parts of the complex dielectric function revealing that the Reststrahlen bands occur when ε_1 is negative. It is interesting to note that the low frequency, very strong TO strontium 62 related mode located at ~87 cm⁻¹ takes ε_1 negative for a significant portion of the far-infrared 63 64 spectrum. It is STO's ability to support SPhP modes across this large spectral range that make it

65 a good candidate for far-infrared nanophotonic applications. While many polar dielectric 66 materials, including α-MoO₃, Al₂O₃, β-Ga₂O₃, and GaAs support SPhP modes in more narrow 67 regions of the mid- and far-infrared, few materials support them over such a wide far-infrared and terahertz spectral range as STO.^{40,44,45} It is this broadband window for SPhPs in the far-68 69 infrared combined with STO supporting two separate SPhP branches across the mid- and far-70 infrared that make the case for STO as a far-infrared nanophotonic platform. Through the 71 application of established techniques such as nanopatterning of geometric structures on the 72 surface, SPhPs in STO should be tunable over a large window of the far-infrared. For example, it 73 has been shown that localized SPhPs can be tuned across the Reststrahlen band by nanopatterning pillars of varying radius on SiC.¹⁵ Applied to STO, these methods should allow 74 75 selective and tunable optical response over the large bandwidth of the far-infrared inside of 76 STO's lower Reststrahlen band paving the way for frequency tailored far-infrared and terahertz 77 sensors, metamaterials, and coherent far-infrared and terahertz sources.

78 There exists a mismatch in the momentum needed to excite a SPhP with a freely propagating 79 photon. Scattering-type scanning near-field optical microscopy (s-SNOM) has been proven to be a particularly useful method to directly excite and probe SPhPs.⁴⁷ In this method, infrared 80 81 radiation is focused to a metal-coated AFM tip which induces strong near fields at the tip apex. 82 These strong near fields interact with the sample underneath and this interaction is encoded in 83 the scattered far-field radiation. The AFM tip is operated in tapping mode to extract the nearfield interaction from the background contributions.⁴⁸ This technique allows nanometer-scale 84 85 optical properties to be studied at a spatial resolution limited only by the radius of the AFM tip apex.⁴⁹⁻⁵³ Due to this high-field confinement, the tip can provide the necessary momentum to 86 excite SPhPs in dielectric materials.⁵⁴ This overcomes the wavevector (momentum) mismatch 87

between the incident light, $k = (\omega/c)$, and the real part of the SPhP wavevector [Re $(k_p) = 2\pi/\lambda_p$]. The complex-valued SPhP wavevector is given by:

$$k_p = \operatorname{Re}(k_p) + i\operatorname{Im}(k_p) = \left(\frac{\omega}{c}\right)\sqrt{\frac{\varepsilon_m\varepsilon_a}{\varepsilon_m + \varepsilon_a}}.$$
⁽¹⁾

Here ω is the angular frequency of incident light, c is the speed of light, ε_m is the complex 90 dielectric function of the medium supporting SPhPs, and ε_a is the complex dielectric function of 91 the ambient medium.⁴² Work has been done using s-SNOM in the mid-infrared spectral range to 92 93 characterize polar dielectric materials such as SiC and low dimensional van der Waals materials, 94 e.g. hexagonal boron nitride. S-SNOM has been utilized to excite, launch and observe interference of these SPhPs by either single line laser or broadband techniques.⁵⁵⁻⁶⁴ Most of the 95 96 work to characterize and realize applications for these SPhPs has been in the mid infrared (>700 97 cm⁻¹) where there are detectors and sources compatible with s-SNOM. For lower SPhP 98 frequencies (< 700 cm⁻¹), options are generally limited to either a synchrotron beamline or free electron laser.65-69 99

100 In this paper, we explore the propagation and interference of the SPhPs on STO by coupling a 101 newly developed, table-top laser sustained plasma light source (LSPLS) to our s-SNOM set up. 102 This newly integrated light source allows ultrabroadband infrared nano-spectroscopy (nano-103 FTIR) to be accessed on a table-top experiment down to frequencies as low as 400 cm⁻¹, limited 104 by the detector cutoff. This allows direct access to excite and probe SPhPs with s-SNOM in the 105 broad far-infrared Reshstrahlen band in STO. First, we introduce this LSPLS, then we 106 demonstrate its ability to probe SPhP resonances in SiO₂, a material whose SPhP resonances are 107 already well characterized with s-SNOM. Then we use the LSPLS and s-SNOM to resolve and

108	map propagating SPhPs on STO launched by a gold (Au) edge. Through analytical modeling of
109	the experimental data, we obtain the dispersion of two SPhP branches.

II. EXPERIMENTAL METHOD

111 We developed in-house a table-top laser-sustained plasma light source to provide the necessary 112 high intensity broadband radiation for nano-FTIR. The LSPLS is a direct upgrade to our previously developed argon plasma light source (APLS).^{20,21,70} A schematic diagram of the 113 114 experimental setup of the LSPLS and s-SNOM can be seen in Fig. 2(a). The LSPLS is described 115 in the Appendix. We performed s-SNOM measurements on STO and SiO₂ samples using a 116 commercial microscope from Neaspec GmbH. Infrared light is focused on to the apex of a metal-117 coated atomic force microscope (AFM) tip. S-SNOM obtains sample information encoded in the 118 scattered light from the tip-sample system. The AFM tip localizes the light to a lateral resolution limited only by the radius of the tip apex.⁴⁴ Broadband near-field spectra can be acquired with 119 120 the s-SNOM instrument and the spectra reveal the broadband, frequency-dependent infrared 121 behavior of the sample at nanometer scale spatial resolution. This method allows us to obtain 122 infrared properties by circumventing the Abbe diffraction limit. It also enables enhanced surface 123 sensitivity when compared to the larger penetration depths of conventional far-field Fourier transform infrared (FTIR) methods.^{71–73} As can be seen in Fig. 2(a), we take broadband nano-124 125 spectroscopy data by coupling the laser-sustained plasma light source to the s-SNOM system. The s-SNOM optical setup (Fig. 2(a)) is similar to that described in our previous works.^{20,21} The 126 127 broadband infrared radiation from the plasma is collected and collimated by an off-axis parabolic 128 (OAP) mirror with a 2-inch focal length. It is reflected at a 45° angle of incidence off an indium 129 tin oxide (ITO) coated glass mirror. This mirror transmits the unwanted near-infrared and visible 130 radiation and reflects the mid- and far- infrared radiation from the plasma. The reflected beam is

131 then focused through a 200 µm pinhole by an OAP with a 4-inch focal length to improve the 132 spatial coherence of the beam. The spatial coherence of the beam incident on the beamsplitter is 133 important for optimal interference between the tip-scattered radiation and the reference beam. 134 After the pinhole, the beam is collimated using an OAP mirror with a 1-inch focal length 135 yielding a beam diameter of about 10 mm. A power of \approx 1 mW is measured in the beam after the 200 μ m diameter pinhole in the spectral range between 400 cm⁻¹ and 5,800 cm⁻¹ (excluding the 136 spectral range between $\approx 1,700$ cm⁻¹ and 2,500 cm⁻¹ due to two-phonon absorption in the 137 138 diamond window of the LSPLS). This beam is then incident on a KRS-5 beamsplitter that 139 transmits part of the beam towards the tip-sample system and reflects part of it towards the 140 movable reference mirror. The transmitted beam is focused by a proprietary OAP on to the AFM 141 tip. The AFM tip used in the experiment is supplied by Neaspec GmbH. The tip is coated with platinum-iridium and has a radius of curvature of ~ 60 nm. The scattered signal from the tip-142 143 sample system is then recollected with the same proprietary OAP and recombined with the beam 144 reflected off the movable reference mirror and brought to a focus at a liquid nitrogen cooled 145 Infrared Associates (FTIR-22-0.100) MCT photoconductive detector with an active area of 10^{-4} cm^2 , a noise equivalent power of 0.84 pW Hz^{-1/2}, a spectral bandwidth of 400 $cm^{-1} - 5,000 cm^{-1}$ 146 147 and a preamp with a 1 MHz bandwidth. The AFM tip is operated in tapping mode with an 148 oscillation frequency of $\tilde{v} \approx 250$ kHz and a tapping amplitude of ~ 80 nm. To suppress the 149 background, the signal recorded by the detector is demodulated at harmonics $n\tilde{\nu}$ of the tip 150 oscillation frequency $\tilde{\nu}$, where the higher harmonics n = 2, 3 contain little to no background contamination. After demodulation, we obtain a scattered amplitude s_n and a scattered phase ϕ_n . 151 152 Initially an AFM topography image of the sample is obtained to map the STO and Au edge 153 location. Note that the STO sample has a 225 nm thick Au film deposited on part of the sample.

154 The tip is brought into contact at the desired location on the sample and the movable reference 155 mirror is scanned a set distance which generates an interferogram. A Fourier transform is applied 156 to this interferogram to generate the near-field spectrum. To eliminate the instrumental features 157 from the spectrum such as the detector responsivity, beam splitter and LSPLS emission features, 158 a normalization spectrum is obtained over a spectrally featureless material such as Au or Si. For 159 point spectroscopy, the tip is kept in the same position on the sample and multiple interferograms 160 are averaged to obtain a high signal to noise ratio spectrum. For a hyperspectral line scan, the tip 161 moves along a set path with a spatial resolution of 1.5 µm collecting a full interferogram at each 162 point of the linescan. A spectrum is obtained upon Fourier transform of an interferogram. The 163 line scan process generates a two-dimensional hyperspectral image where the x-axis is the real 164 space location of the tip and the y-axis is the frequency-dependent spectrum of the near-field 165 amplitude or phase at that location. All the spectra in this paper, including the hyperspectral line scan, are taken with a spectral resolution of 12.5 cm⁻¹. The spectra obtained with the 166 167 hyperspectral line scan are zero-padded to improve image quality. The beam path and s-SNOM 168 system is enclosed in a dry and CO₂-free air purge to eliminate unwanted spectral features from 169 water and CO₂.

170

III. RESULTS AND DISCUSSION

First, a calibration sample was studied to observe known SPhP resonances in SiO₂. The sample studied consisted of ≈ 100 nm layer of SiO₂ over silicon. We obtain an ultrabroadband near-field spectrum over the 400 cm⁻¹ – 1250 cm⁻¹ frequency (v) range which resolves two separate SPhP resonances that occur in SiO₂ seen in the amplitude and phase [Fig. 2(b) and 2(c) respectively]. The higher lying resonance at 1130 cm⁻¹ has been characterized in many other near-field works^{20,21,74,75} while the lower lying resonance at 450 cm⁻¹ has only been observed by

177	s-SNOM utilizing an infrared synchrotron beamline. ⁶⁹ Our observation of this lower lying mode
178	with our tabletop LSPLS system demonstrates the powerful utility of this source for far-infrared
179	near-field nanospectroscopy. We then perform broadband near-field infrared experiments on
180	single crystal STO. We obtain amplitude and phase spectra [Fig. 2(d) and 2(e)] on STO very far
181	(>500 μ m) from the Au edge to characterize the near-field spectrum of STO. We see the two
182	SPhP resonances that have been observed previously on bulk STO with the sharper low
183	frequency resonance occurring at ≈ 425 cm ⁻¹ and the broader high frequency resonance occurring
184	at ≈ 675 cm ⁻¹ [Ref. 21]. The peaks occur inside the respective Reststrahlen bands in STO [Fig.
185	1(a)], and arise from resonant near-field coupling between STO and the AFM probe geometry.
186	We then map the SPhPs in STO by obtaining an amplitude and phase resolved hyperspectral
187	line scan in the vicinity of the Au edge. We orient the sample such that the Au edge is
188	perpendicular to the in-plane projection of the tip illumination wavevector. Figure 3(a) shows a
189	basic schematic of how the tip is scanned a distance away from the Au edge while the broadband
190	illumination, having a focused spot size diameter of $\sim 120 \ \mu m$ set by the pinhole, allows
191	simultaneous tip illumination while launching SPhPs from the Au edge. Figure 3(b) and 3(c)
192	show the amplitude and phase resolved near-field hyperspectral line scan showing the two SPhP
193	resonances that occur in STO. As the tip is scanned away from the Au edge frequency dependent
194	interference fringes can be seen in both the resonances. Taking single frequency cuts (Fig. 3(d)
195	and 3(e)) of the hyperspectral line scan demonstrate clear fringes in both the amplitude and phase
196	whose fringe spacing decrease with increasing illumination frequency. Another way to view this
197	Au edge distance dependent SPhP interference is to look at the spectra as a function of distance.
198	To increase the signal-to-noise ratio (SNR) from the hyperspectral line scan, point spectra were
199	obtained by placing the tip at select distances from the Au edge in the same location and

experimental geometry as the hyperspectral line scan. For these spectra, 10 interferograms were
collected and averaged to reduce the noise in the amplitude and phase revealing clear peak shifts
in the spectrum that result from the propagating SPhPs interfering with the incident tip
illumination. These peak shifts match the hyperspectral line scan spectra at the same distance.
Figure 3(f) and 3(g) show the amplitude and phase spectra obtained at select distances from the
Au edge.

206 Our experimental geometry is similar to that used in previous works: SPhPs launched from a straight Au edge on SiC and boron nitride slab,^{55,76,77} infrared plasmon polaritons launched from 207 a straight Au edge on graphene,⁷⁸ and visible plasmon polaritons on Au launched from a slit.⁷⁹ 208 209 As already described by Huber *et al*, the incident field at the tip is a superposition of the incident illumination, E_i , at the tip position, x, and the Au edge launched evanescent SPhP field at the tip 210 position, $E_p(x, z) = f_0 E_0 e^{i(k_{p,x}x + k_{p,z}z + \varphi_0)}$, where $E_0 = E_i e^{-ik\cos(\alpha)x}$ is the illumination field at 211 the Au edge.⁵⁵ Here, $k_{p,x}$ and $k_{p,z}$ are the complex valued SPhP dispersion relation in the x and z 212 213 direction and α is the angle between the sample surface and the direction of the incident light (α 214 is set to be 30° by our instrument). We assume plane wave illumination with wavevector k. We account for the relative field amplitude, $f_0 = |E_p(x = 0, z = 0)|/|E_i|$, and excitation phase, φ_0 215 based on experimental data. We represent the scattered field from the tip as $E_s = \alpha_{eff}(z)[E_p +$ 216 E_i], where $\alpha_{eff}(z)$ is the effective polarizability describing the near-field interaction between the 217 218 tip and sample. Since the decay length of the surface polariton field is much larger than the tapping amplitude of the tip we can simplify the model by approximating $E_p(x, z) \approx E_p(x, 0)$. 219 All together we can express the signal scattered from the tip at the n^{th} harmonic of the tapping 220 221 frequency to be:

$$E_{s,n}(x) = \alpha_{\text{eff},n} \left[1 + f_0 e^{i \left[(k_{p,x} - k\cos(\alpha))x + \varphi_0 \right]} \right] E_i, \tag{2}$$

with $\alpha_{eff,n}$ representing the n^{th} harmonic of $\alpha_{eff}(z)$ which is constant when scanning over 222 homogenous materials.^{48,80} Using Eq. (2), the experimental fringe spacing at each frequency was 223 fit (Fig. 4(a)-4(d)) to extract the complex-valued SPhP wavevector, $k_{p,x}$. The real part, Re($k_{p,x}$), 224 depends on the fringe spacing, and its dispersion is plotted in Fig. 4(e). The data points of 225 $\operatorname{Re}(k_{n,x})$, shown on the dispersion plot lie close to the theoretical dispersion calculated from the 226 generic SPhP theory [Eq. (1)] using published STO optical constants (Fig. 4(e)).⁴⁶ Our geometry 227 228 for mapping propagating polaritons is distinct from the similar case where a standing wave is 229 measured between tip launched and edge reflected surface plasmon polariton fringes seen in reports on graphene⁸¹ and hexagonal boron nitride.⁶³ In our work, the radially decaying tip 230 launched SPhPs are weaker than the SPhPs launched from the straight Au edge.⁶¹ It is worth 231 232 noting that we were able to extract two accurate SPhP dispersions simultaneously over a broad 233 spectral range compared to similar studies on SiC thus proving the utility of the LSPLS and the 234 potential of STO for far-infrared photonic applications.

The propagation length of the SPhPs, L_p , is related to the imaginary part of the SPhP 235 wavevector by $L_p = 1/\text{Im}(k_{p,x})$. A comparison of the propagation lengths from our $k_{p,x}$ 236 237 extracted from the fringe spacings and the propagation lengths calculated from generic theory 238 (Eq. 1) is shown in the inset of Fig. 4(e). The propagation length of SPhP in the far-IR 239 Reststrahlen band is longer than that of the SPhP in the mid-IR Reststrahlen band. This is likely 240 due to the relatively lower damping (and lower ε_2) in the far-IR Reststrahlen band (see Fig. 1b) 241 inset). Interestingly, the high frequency side of each SPhP shows good agreement with generic theory (eq. 1) while the low frequency side of each SPhP does not. We attribute this 242

disagreement between experiment and generic SPhP theory (eq. 1) on the low frequency side of
the SPhPs to additional damping introduced by the coupling of the SPhPs to the surface
plasmon-polaritons along the shaft of the AFM tip. Our previous work demonstrates that the farfield scattering from the tip is off-resonance at frequencies about 400 cm⁻¹ and about 650 cm⁻¹
[Ref. 21]. These are the frequencies near which the SPhP damping deviates from generic theory
(eq. 1) prediction. At the tip's off-resonance frequencies, the coupling of the propagating SPhP
modes to the tip shaft could be damped.

250

IV. CONCLUSIONS AND OUTLOOK

251 To conclude, we have mapped interference patterns of propagating SPhPs on the surface of 252 single crystal STO in the far- and mid-infrared spectral range. This is enabled by a new, table-top 253 thermal broadband source based on a laser-sustained plasma that provides sufficient intensity in 254 the far- and mid-infrared for ultrabroadband s-SNOM. We have demonstrated mid- and far-255 infrared hyperspectral imaging of SPhPs with nanometer scale spatial resolution. This work 256 further makes the case for STO as a platform for far-infrared nano-photonics. Interesting paths forward include spatially confining these SPhPs to thin films or ultrathin membranes^{82,83} of STO 257 258 as well incorporating subwavelength nanophotonic structures on STO that guide and direct these 259 SPhPs at wavelengths across the lower Reststrahlen band to explore STO's uniquely broad 260 spectral range supporting SPhPs in the terahertz. It has been shown that STO can be strained to be ferroelectric at room temperature in both thin films and membranes.^{84,85} The ferroelectric 261 distortion can be probed by observing a shift in the SPhP resonance wavelength.^{23,86} It would be 262 263 interesting to probe how the SPhP propagation is affected by ferroelectric domains and at domain 264 walls in strained STO films and membranes. The laser sustained plasma light source enables a 265 table-top method for far-infrared ultrabroadband nano-spectroscopy. There is potential for future

266 improvements involving alternative detectors with lower frequency cutoffs to delve deeper into 267 the far-infrared and terahertz because the CVD diamond window of our infrared light source is 268 transparent to all of the far-infrared and terahertz frequencies.

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APPENDIX: LASER SUSTAINED PLASMA LIGHT SOURCE

274 Similar to the Argon Plasma Light Source (APLS), the Laser Sustained Plasma Light Source (LSPLS) is comprised of an aluminum vessel with windows for optical access and tungsten 275 electrodes for igniting the plasma.²⁰ For the LSPLS, this vessel is pressurized between 15 - 20276 277 atmospheres gauge of high purity xenon gas. A high voltage pulse generates an arc across two 278 electrodes which is then sustained by a constant current. The upgrade consists of a near-infrared 279 diode laser with $\approx 1 \,\mu m$ wavelength in the vicinity of a strong xenon line, and incident power of 280 \approx 85 W. The laser light is brought to a focus in the gap between these electrodes where the 281 plasma is being sustained by the electric current. The current is then terminated, and the plasma 282 is sustained by the laser at its focus yielding a highly stable and brilliant broadband infrared 283 source. The aluminum vessel has two anti-reflective coated quartz windows: one window allows 284 us to couple the incident laser to sustain the plasma, and the other window allows the unabsorbed 285 laser light to exit and be terminated at an external beam dump after passing through a beam 286 splitter that sends a small portion of the intensity to a power meter to measure the laser power 287 transmitted through the plasma. A CVD diamond window is clamped to the pressure vessel via a 288 viton O-ring. This material allows access to the broadband infrared radiation of the plasma into

289 the mid- and far-infrared spectral range while providing the necessary thermal and mechanical 290 properties necessary to seal the pressure vessel. There are major advantages of incorporating the 291 laser to sustain the plasma. In the current- sustained plasma in the APLS, a significant portion of 292 the power is dissipated by the heat conducted by the electrodes. The advantage of sustaining the 293 plasma with a laser is that the power is more efficiently transferred to useable broadband 294 radiation while increasing the lifetime of the light source by significantly lowering the overall 295 usage time of the electrodes. Secondly, the plasma becomes more localized to the focus of the 296 laser, allowing a smaller emission volume which is advantageous for microscopy.

297 To compare the SNR of our LSPLS with the previous APLS from Ref. [20,21], we show 100% 298 lines taken over gold using the same tip and detector (Fig. 5). A 100% line is the ratio of two 299 spectra obtained one after the other under identical conditions. We note that the integration time 300 for acquisition of spectra with the LSPLS is less than half the integration time for acquisition of 301 spectra with the APLS. Spectra were demodulated at the second harmonic of the tip oscillation frequency. Spectra were obtained with spectral resolution of $\delta \tilde{\nu} = 12.5$ cm⁻¹. Gold spectra 302 303 obtained with the APLS employed an integration time of 120 minutes per spectrum. Gold spectra 304 obtained with the LSPLS employed an integration time of 55 minutes per spectrum. The long 305 integration times are required due to the lower detectivity of our wideband MCT detector with low frequency cutoff of 400 cm⁻¹ compared to the commonly used mid-infrared MCT detectors 306 such as the high detectivity Kolmar (KLD-0.1J1/208) that has a low frequency cutoff of 750 307 cm⁻¹. Using the normalized signal-to-noise ratio, NSNR = $\frac{SNR}{8\tilde{\alpha}\sqrt{r}}$, defined in Ref. [74], we can 308 309 compare the signal of our LSPLS with the previous APLS. For the demodulated second harmonic (n = 2) spectra in the range of 400 cm⁻¹ to 850 cm⁻¹, we obtain an NSNR of 0.009 and 310 311 0.026 for the APLS and the LSPLS respectively. This result shows that we see almost a 3-fold

312	increase in our NSNR with the LSPLS system. This leads to lower integration times (of the order		
313	of minutes) for obtaining a spectrum, especially on samples with SPhP resonances. For example,		
314	it took about four minutes to acquire each spectrum in the hyperspectral line scan on STO (Fig. 3		
315	b, c).		
316			
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555 **Figure captions:**

FIG 1. (a) Reflectance of STO demonstrating the two Reststrahlen bands. (b) Real (ε_1) and imaginary (ε_2) parts of the dielectric function with the optical phonon modes indicated by vertical dashed lines. The inset shows the zoomed in view of the frequency-dependent real (black) and imaginary (red) parts of the dielectric function. The shaded region shows the negative ε_1 regions. The optical constants for STO were taken from Ref. [46].

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FIG. 2. (a) Schematic of the beam path used in our LSPLS system with the red representing the near-infrared laser used to sustain the plasma and the yellow representing the broadband radiation from the plasma. Broadband nano-FTIR point spectra obtained with the LSPLS setup on 100 nm SiO₂ on Si showing n = 2 amplitude (b) and phase (c) referenced to Si. The reference spectrum on Si is shown in the inset of (b). The n = 2 amplitude (d) and phase (e) point spectra of bulk STO referenced to an Au film deposited on part of the STO. The spectra on STO were obtained far (>500 µm) from the Au film. The phase is indeterminate in the spectral regions depicted by the gray areas in (e) because the scattering amplitude from STO is negligibly smallin these spectral regions.

572	FIG. 3. (a) Schematic side-view of the experiment showing the incident illumination and tip-
573	sample system for studying the SPhPs on STO. The tip, starting over Au, is scanned away from
574	the Au edge while the broadband $n = 2$ amplitude (b) and phase (c) spectra are measured. The
575	spectra are normalized to an Au reference spectrum. Amplitude (d) and phase (e) line cuts at
576	representative frequencies from (b) and (c) respectively demonstrating frequency dependent
577	fringe spacings. The $n = 2$ amplitude (f) and phase (g) spectra at different distances from the Au
578	edge (indicated by arrows in (b)) exhibit spectral changes due to the SPhP interference. The
579	phase is indeterminate in the spectral regions depicted by horizontal black lines in (c) and the
580	gray areas in (g) because the scattering amplitude from STO is negligibly small in these spectral
581	regions.

FIG. 4. (a)–(d) Experimental near-field infrared amplitude line cuts from Fig. 3(b) showing
fringe spacings at select frequencies. Also shown are fits based on Eq. (2). (e) SPhP dispersion
obtained from analysis of experimental results (Eq. 2) compared to the SPhP dispersion from
generic theory (Eq. 1). Also included is the light line in vacuum. ((e) inset) Propagation length of
SPhPs calculated from generic theory (Eq. 1) compared to the analysis of experimental results
(Eq. 2).

- 590 FIG. 5. A 100% line taken on gold (Au) using the APLS (Ref. 21) and a 100% line taken on gold
- 591 with the LSPLS in less than half the integration time compared to the APLS (see text for details).









